NPN Triple Diffused Planar Silicon Transistor



2SD2251

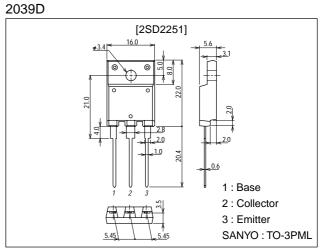
Color TV Horizontal Deflection Output Applications

Features

- \cdot High speed (t_f=100ns typ).
- \cdot High breakdown voltage (V_{CBO} = 1500V).
- \cdot High reliability (Adoption of HVP process).
- \cdot On-chip damper diode.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		1500	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		7	A
Collector Current (Pulse)	ICP		20	А
Collector Dissipation	PC		3.0	W
	'C	Tc=25°C	60	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ІСВО	V _{CB} =800V			10	μΑ
	ICES	V _{CE} =1500V			1.0	mA
Collector-to-Emitter Saustain Voltage	V _{CEO(sus)}	I _C =100mA, I _B =0	800			V
Emitter Cutoff Current	IEBO	V _{EB} =4V	40		130	mA
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =5A, I _B =1.0A			5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =5A, I _B =1.0A			1.5	V

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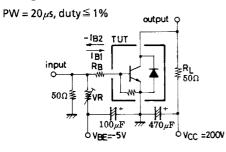
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

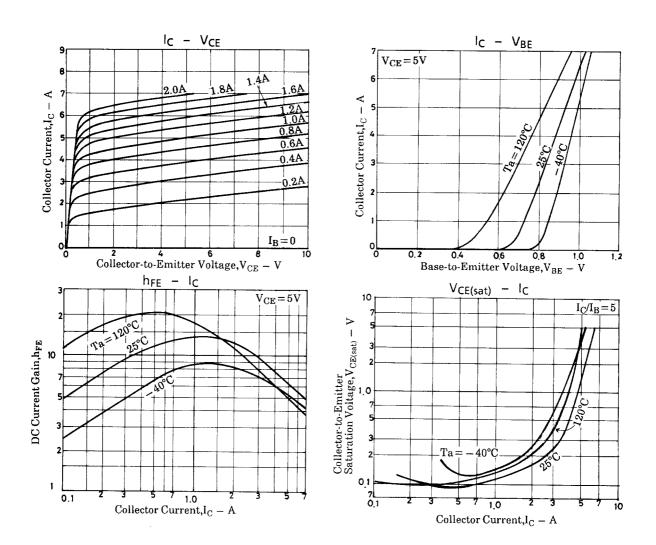
31099TH (KT)/90794MT (KOTO) BX-0937, 8-7561, 8165 No.3741-1/4

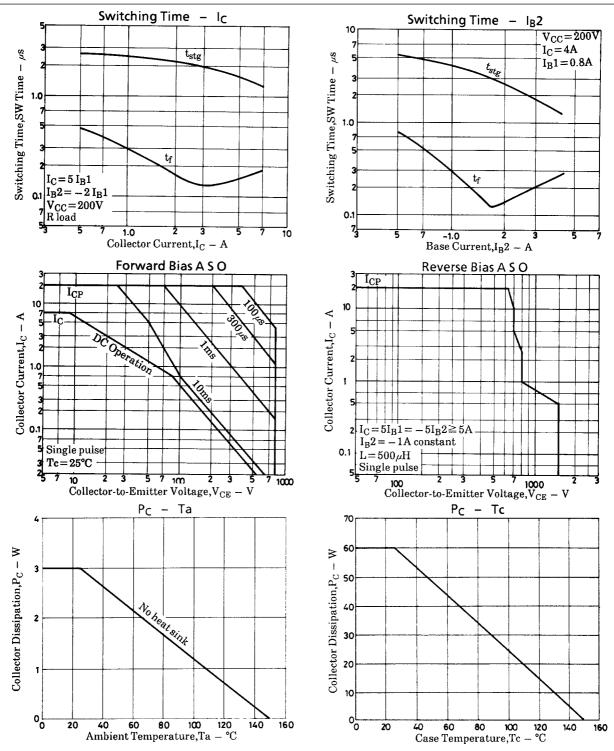
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =1A	8			
	h _{FE} 2	V _{CE} =5V, I _C =5A	5		8	
Diode Forward Voltage	VF	I _{EC} =7A, I _B =0			2.0	V
Fall Time	t _f	I _C =4A, I _B 1=0.8A, I _B 2=-1.6A		0.1	0.3	μs

Switching Time Test Circuit







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